Z0109NA

Logic level four-quadrant triac Rev. 04 — 4 August 2009

Product data sheet

Product profile 1.

1.1 General description

Passivated sensitive gate 4-Q triac in a SOT54 plastic package

1.2 Features and benefits

- Direct interfacing to logic level ICs
- Direct interfacing to low power gate drive circuits
- High blocking voltage of 800V
- Sensitive gate in four quadrants

1.3 Applications

- General purpose low power motor control
- Home appliances

- Industrial process control
- Low power AC Fan controllers

1.4 Quick reference data

Table 1. **Quick reference**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{lead} ≤ 38 °C; see <u>Figure 1</u> and <u>4</u>	-	-	1	Α
I _{TSM}	non-repetitive peak on-state current	full sine wave; t_p = 20 ms; $T_{j(init)}$ = 25 °C; see Figure 2 and 3	-	-	8	Α
		full sine wave; $t_p = 16.7 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$	-	-	8.5	Α
Static ch	aracteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V; } T_j = 25 \text{ °C; } T2 + G-;$ see <u>Figure 6</u>	-	-	10	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; T2- G-$	-	-	10	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; T2+ G+$	-	-	10	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; T2- G+$	-	-	10	mA



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2. Pinning information

Table 2. Pinning information

	_	•				
Pin	Symbol	Description	Simplified outline	Graphic symbol		
1	T2	main terminal 2		K I		
2	G	gate		T2T1		
3	T1			sym051		
			SOT54 (TO-92)			

3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
Z0109NA	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54	

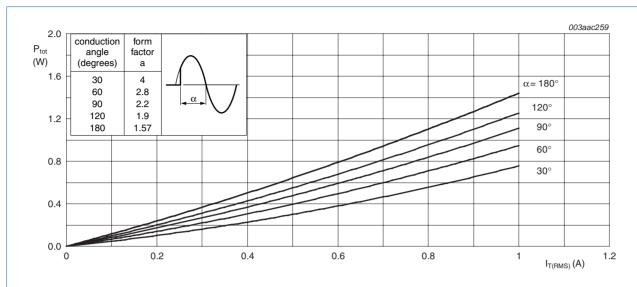
4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

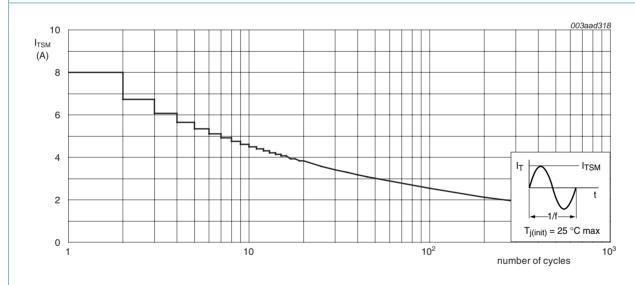
Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{lead} ≤ 38 °C; see <u>Figure 1</u> and <u>4</u>	-	1	Α
dI _T /dt	rate of rise of on-state	$I_T = 1 \text{ A}$; $I_G = 20 \text{ mA}$; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$; $T2 + G + G$	-	50	A/µs
	current	$I_T = 1 \text{ A}$; $I_G = 20 \text{ mA}$; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$; $T2 + G$	-	50	A/µs
		$I_T = 1 \text{ A}$; $I_G = 20 \text{ mA}$; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$; T2- G-	-	50	A/µs
		$I_T = 1 \text{ A}$; $I_G = 20 \text{ mA}$; $dI_G/dt = 100 \text{ mA/}\mu\text{s}$; T2- G+	-	20	A/µs
I_{GM}	peak gate current		-	1	Α
P_GM	peak gate power		-	2	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
I _{TSM}	non-repetitive peak on-state current	full sine wave; t_p = 20 ms; $T_{j(init)}$ = 25 °C; see <u>Figure 2</u> and <u>3</u>	-	8	Α
		full sine wave; $t_p = 16.7 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$	-	8.5	Α
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	0.32	A ² s
$P_{G(AV)}$	average gate power		-	0.1	W

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 α = conduction angle

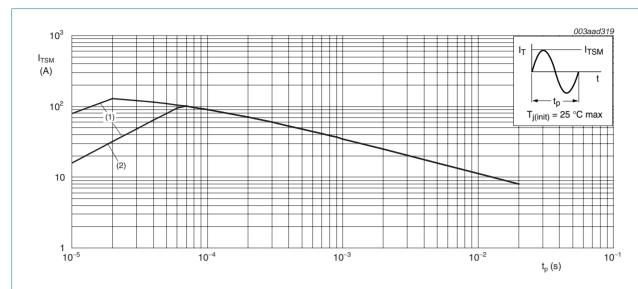
Fig 1. Total power dissipation as a function of RMS on-state current; maximum values



f = 50 Hz

Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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 $t_p \le 20$ ms; (1) is dI_T/dt limit; (2) is T2 - G + quadrant limit

Fig 3. Non-repetitive peak on-state current as a function of pulse width; maximum values

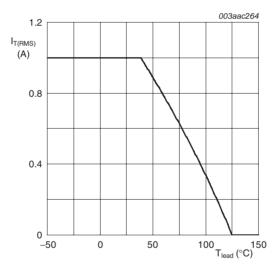


Fig 4. RMS on-state current as a function of lead temperature; maximum values

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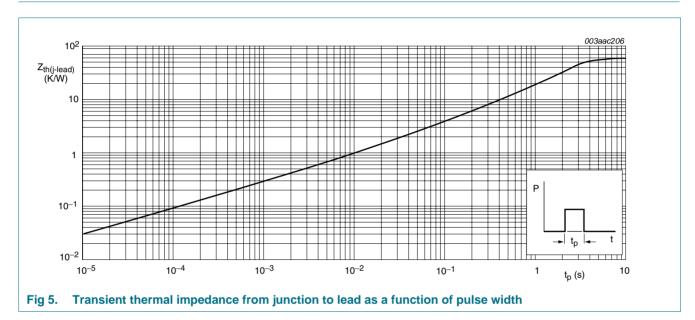
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Thermal characteristics 5.

Thermal characteristics Table 5.

Product data sheet

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		-	150	-	K/W
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	Full cycle; see Figure 5	-	-	60	K/W

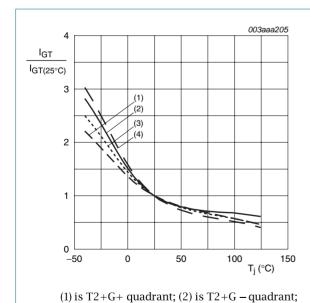


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6. Characteristics

Table 6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; T2+ G-; see Figure 6$	-	-	10	mA
		V _D = 12 V; T _j = 25 °C; T2- G-	-	-	10	mA
		V _D = 12 V; T _j = 25 °C; T2+ G+	-	-	10	mΑ
		V _D = 12 V; T _j = 25 °C; T2- G+	-	-	10	mA
IL	latching current	$V_D = 12 \text{ V; T}_j = 25 \text{ °C; I}_G = 0.1 \text{ A; T2+ G-;}$ see Figure 7	-	-	25	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; I_G = 0.1 \text{ A}; T2+ G+$	-	-	15	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; I_G = 0.1 \text{ A}; T2-G+$	-	-	15	mA
		$V_D = 12 \text{ V}; T_j = 25 \text{ °C}; I_G = 0.1 \text{ A}; T2- G-$	-	-	15	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; see <u>Figure 10</u>	-	-	10	mA
V_{T}	on-state voltage	I _T = 1 A; see <u>Figure 8</u>	-	1.3	1.6	V
V_{GT}	gate trigger voltage	$I_T = 0.1 \text{ A}$; $V_D = 12 \text{ V}$; $T_j = 25 \text{ °C}$; see Figure 9	-	-	1.3	V
		$I_T = 0.1 \text{ A}; V_D = 800 \text{ V}; T_j = 125 \text{ °C}$	0.2	-	-	V
I _D	off-state current	V _D = 800 V; T _j = 125 °C	-	-	0.5	mA
Dynamics	charateristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T_j = 110 °C; gate open circuit; see <u>Figure 11</u>	50	-	-	V/µs
dV _{com} /dt	rate of rise of commutating voltage	$V_D = 400 \text{ V}; T_j = 110 ^{\circ}\text{C}; dI_{com}/dt = 0.44 \text{ A/ms};$ gate open circuit	2	-	-	V/µs



(3) is T2 – G – quadrant; (4) is T2 – G+ quadrantFig 6. Normalized gate trigger current as a function of junction temperature

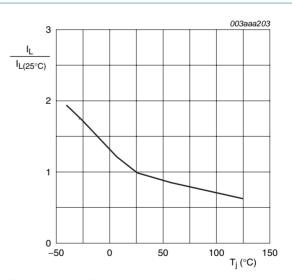
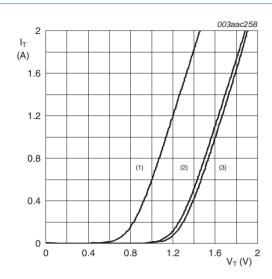


Fig 7. Normalized latching current as a function of junction temperature

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$$V_0 = 1.254 \text{ V; } R_c = 0.31 \Omega$$

- $\begin{aligned} &\mathbf{V}_0 = 1.254 \; \mathbf{V}; \mathbf{R}_{\mathrm{s}} = 0.31 \, \Omega \\ &(1) \; T_j = 125 \; \mathbf{C}; \; \text{typical values} \\ &(2) \; T_j = 125 \; \mathbf{^{\circ}C}; \; \text{maximum values} \\ &(3) \; T_j = 25 \; \mathbf{^{\circ}C}; \; \text{maximum values} \end{aligned}$

Fig 8. On-state current as a function of on-state voltage

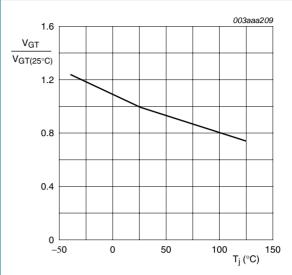


Fig 9. Normalized gate trigger voltage as a function of junction temperature

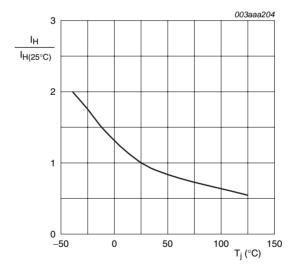


Fig 10. Normalized holding current as a function of junction temperature

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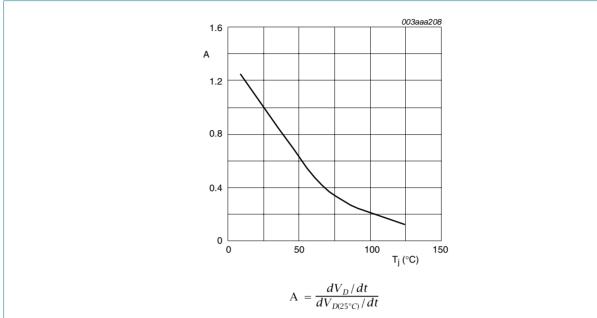


Fig 11. Normalized critical rate of rise of off-state voltage as a function of junction temperature;typical values

7. Package outline

Plastic single-ended leaded (through hole) package; 3 leads

SOT54

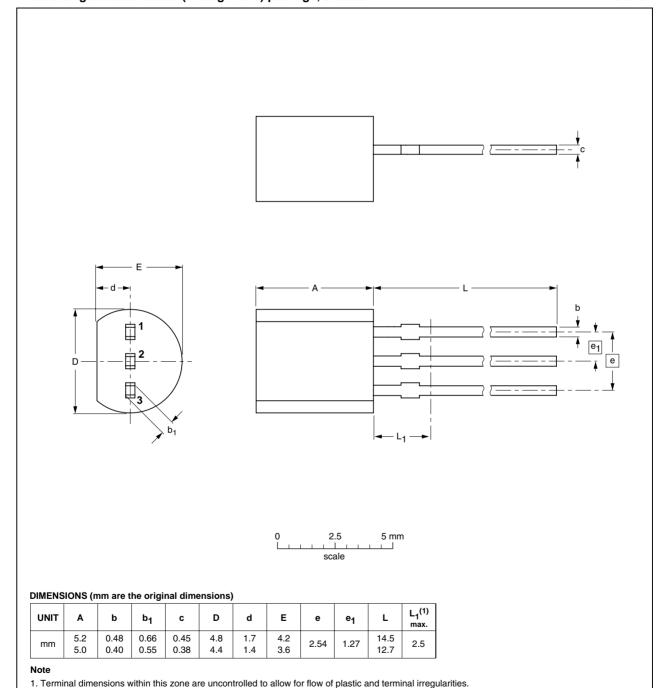


Fig 12. Package outline SOT54 (TO-92)

IEC

OUTLINE

VERSION

SOT54

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JEITA

SC-43A

EUROPEAN

PROJECTION

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ISSUE DATE

04-06-28

04-11-16

REFERENCES

JEDEC

TO-92

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8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
Z0109NA_4	20090804	Product data sheet	-	Z0109NA_3
Modifications:	 Various ch 	anges to content.		
Z0109NA_3	20090623	Product data sheet	-	Z0103_07_09_SERIES-02
Z0103_07_09_SERIES-02 (9397 750 10102)	20020912	Product data	-	Z0103_07_09_SERIES-01
Z0103_07_09_SERIES-01 (9397 750 09419)	20020411	Product data	-	-

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9. Legal information

9.1 Data sheet status

Document status [1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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